CLAIMS

[Claim 1]

A substrate wafer comprising a central convex or a central concave warp and wherein a nanotopography in 2 mm x 2 mm in SQMM is less than 10 nm, and a warp value w [μm] is 40 μm or more.

[Claim 2]

The substrate wafer according to claim 1,

wherein the nanotopography is less than 5 nm.